

MJL21193 (PNP), MJL21194 (NPN)

Silicon Power Transistors

The MJL21193 and MJL21194 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

Features

- Total Harmonic Distortion Characterized
- High DC Current Gain
- Excellent Gain Linearity
- High SOA
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|----------------|----------------|--------------------------|
| Collector-Emitter Voltage | V_{CEO} | 250 | Vdc |
| Collector-Base Voltage | V_{CBO} | 400 | Vdc |
| Emitter-Base Voltage | V_{EBO} | 5 | Vdc |
| Collector-Emitter Voltage - 1.5 V | V_{CEX} | 400 | Vdc |
| Collector Current - Continuous | I_C | 16 | Adc |
| Collector Current - Peak (Note 1) | I_{CM} | 30 | Adc |
| Base Current - Continuous | I_B | 5 | Adc |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 200 1.43 | W W/ $^\circ\text{C}$ |
| Operating and Storage Junction Temperature Range | T_J, T_{stg} | -65 to +150 | $^\circ\text{C}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2\%$

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--------------------------------------|-----------------|-----|---------------------------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 0.7 | $^\circ\text{C}/\text{W}$ |

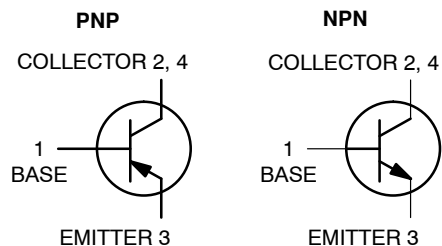
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



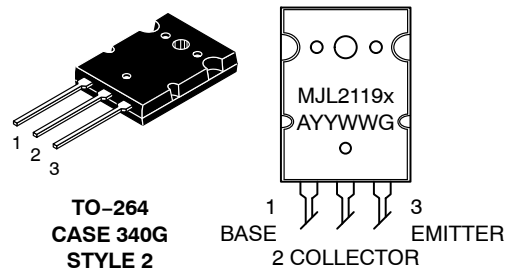
ON Semiconductor®

<http://onsemi.com>

16 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS, 200 WATTS



MARKING DIAGRAM



x = 3 or 4
A = Assembly Location
YY = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------|---------------------|-----------------|
| MJL21193G | TO-264 (Pb-Free) | 25 Units / Rail |
| MJL21194G | TO-264 (Pb-Free) | 25 Units / Rail |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

OFF CHARACTERISTICS

| | | | | | |
|--|---------------|-----|---|-----|-----------------|
| Collector-Emitter Sustaining Voltage ($I_C = 100\text{ mAdc}$, $I_B = 0$) | $V_{CE(sus)}$ | 250 | - | - | Vdc |
| Collector Cutoff Current ($V_{CE} = 200\text{ Vdc}$, $I_B = 0$) | I_{CEO} | - | - | 100 | μAdc |
| Emitter Cutoff Current ($V_{CE} = 5\text{ Vdc}$, $I_C = 0$) | I_{EBO} | - | - | 100 | μAdc |
| Collector Cutoff Current ($V_{CE} = 250\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ Vdc}$) | I_{CEX} | - | - | 100 | μAdc |

SECOND BREAKDOWN

| | | | | | |
|---|-----------|-------------|--------|--------|-----------------|
| Second Breakdown Collector Current with Base Forward Biased ($V_{CE} = 50\text{ Vdc}$, $t = 1\text{ s}$ (non-repetitive)) ($V_{CE} = 80\text{ Vdc}$, $t = 1\text{ s}$ (non-repetitive)) | $I_{S/b}$ | 4.0 2.25 | - - | - - | A _{dc} |
|---|-----------|-------------|--------|--------|-----------------|

ON CHARACTERISTICS

| | | | | | |
|---|---------------|---------|--------|----------|-----|
| DC Current Gain ($I_C = 8\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$) ($I_C = 16\text{ Adc}$, $I_B = 5\text{ Adc}$) | h_{FE} | 25 8 | - - | 75 - | |
| Base-Emitter On Voltage ($I_C = 8\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$) | $V_{BE(on)}$ | - | - | 2.2 | Vdc |
| Collector-Emitter Saturation Voltage ($I_C = 8\text{ Adc}$, $I_B = 0.8\text{ Adc}$) ($I_C = 16\text{ Adc}$, $I_B = 3.2\text{ Adc}$) | $V_{CE(sat)}$ | - - | - - | 1.4 4 | Vdc |

DYNAMIC CHARACTERISTICS

| | | | | | |
|--|----------|--------|-------------|--------|-----|
| Total Harmonic Distortion at the Output $V_{RMS} = 28.3\text{ V}$, $f = 1\text{ kHz}$, $P_{LOAD} = 100\text{ W}_{RMS}$ (Matched pair $h_{FE} = 50 @ 5\text{ A}/5\text{ V}$) | T_{HD} | - - | 0.8 0.08 | - - | % |
| Current Gain Bandwidth Product ($I_C = 1\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 1\text{ MHz}$) | f_T | 4 | - | - | MHz |
| Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f_{test} = 1\text{ MHz}$) | C_{ob} | - | - | 500 | pF |

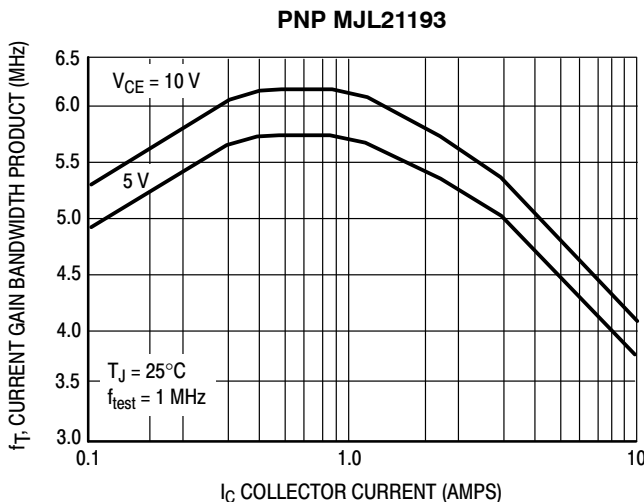


Figure 1. Typical Current Gain Bandwidth Product

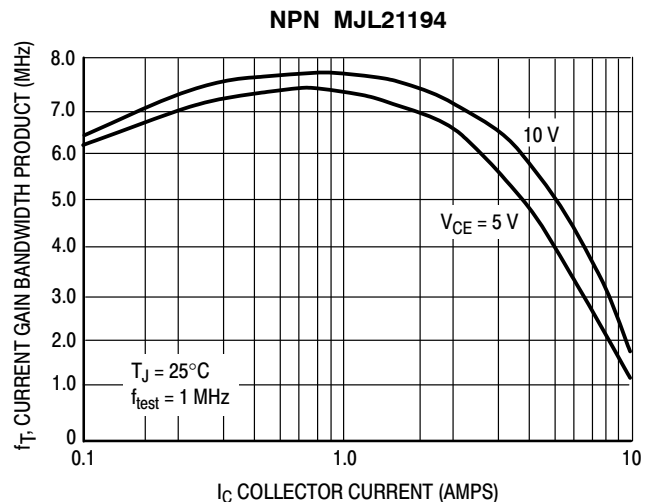


Figure 2. Typical Current Gain Bandwidth Product

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TYPICAL CHARACTERISTICS

PNP MJL21193

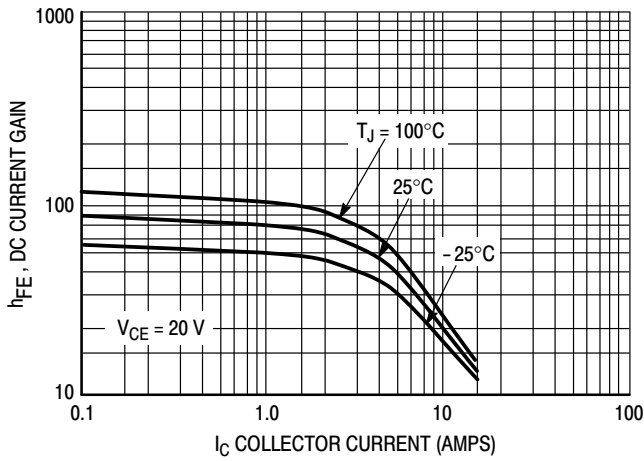


Figure 3. DC Current Gain, $V_{CE} = 20\text{ V}$

NPN MJL21194

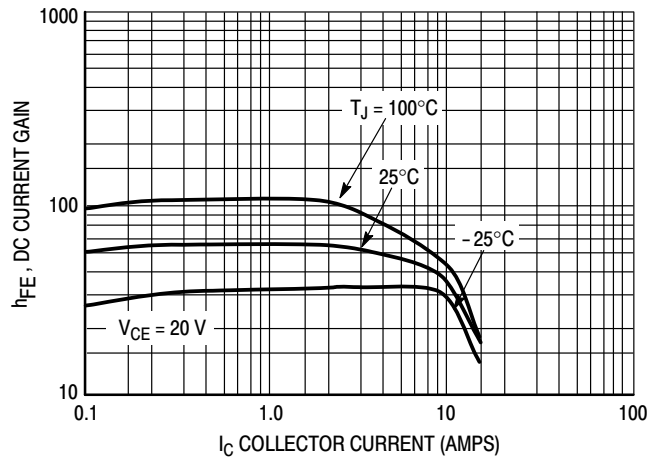


Figure 4. DC Current Gain, $V_{CE} = 20\text{ V}$

PNP MJL21193

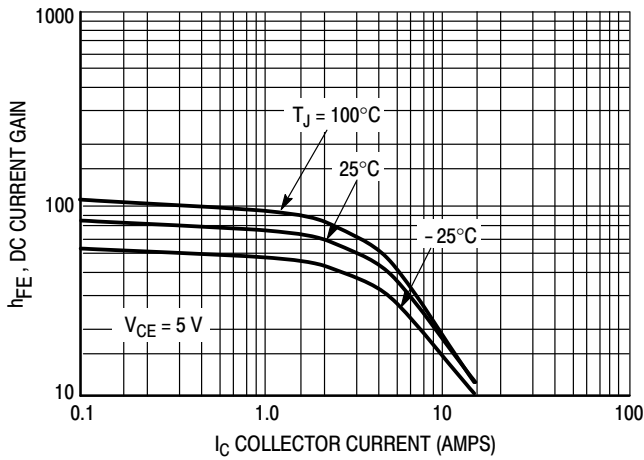


Figure 5. DC Current Gain, $V_{CE} = 5\text{ V}$

NPN MJL21194

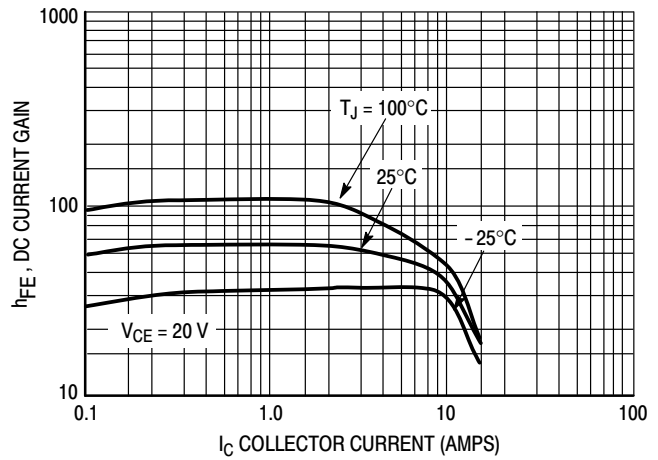


Figure 6. DC Current Gain, $V_{CE} = 5\text{ V}$

PNP MJL21193

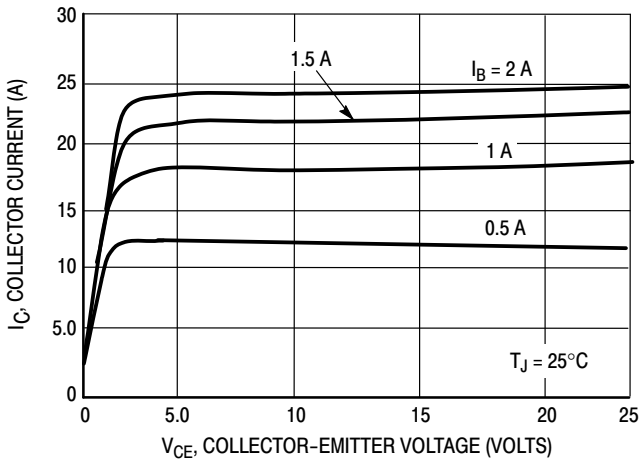


Figure 7. Typical Output Characteristics

NPN MJL21194

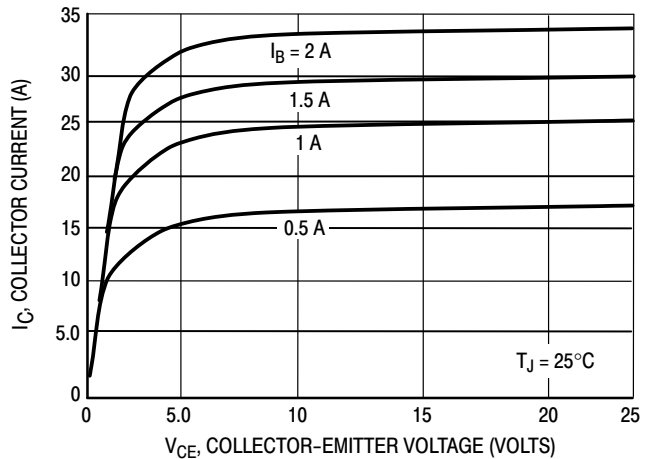


Figure 8. Typical Output Characteristics

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TYPICAL CHARACTERISTICS

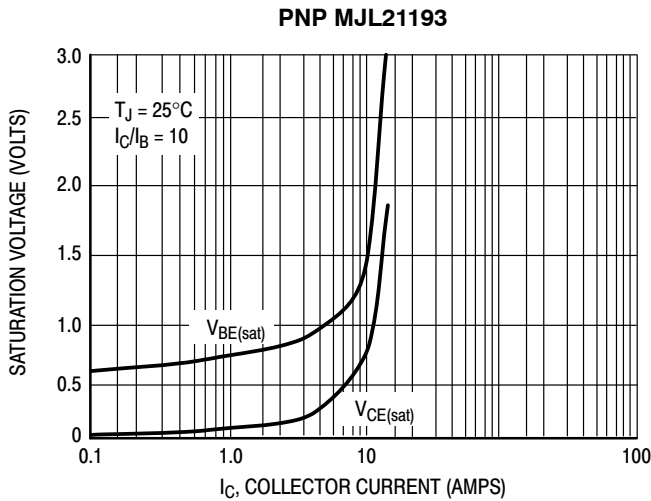


Figure 9. Typical Saturation Voltages

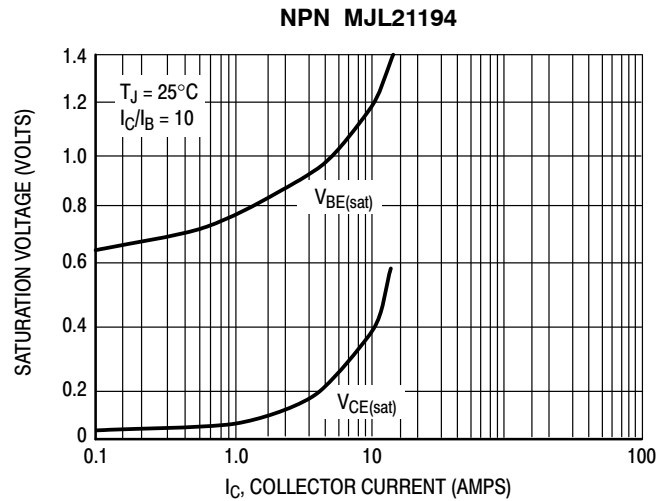


Figure 10. Typical Saturation Voltages

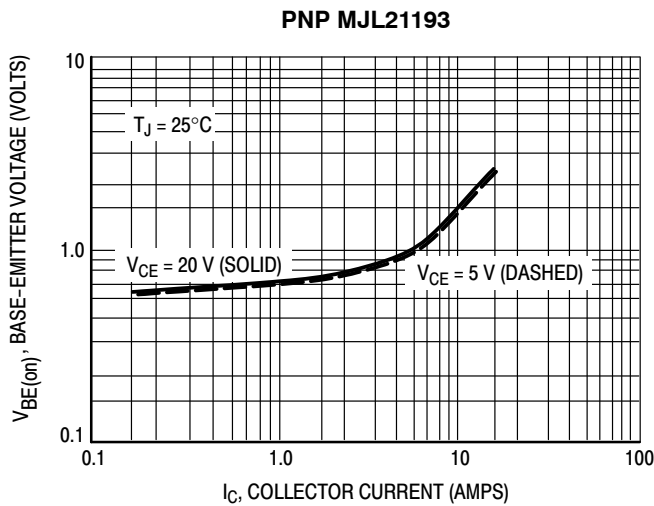


Figure 11. Typical Base-Emitter Voltage

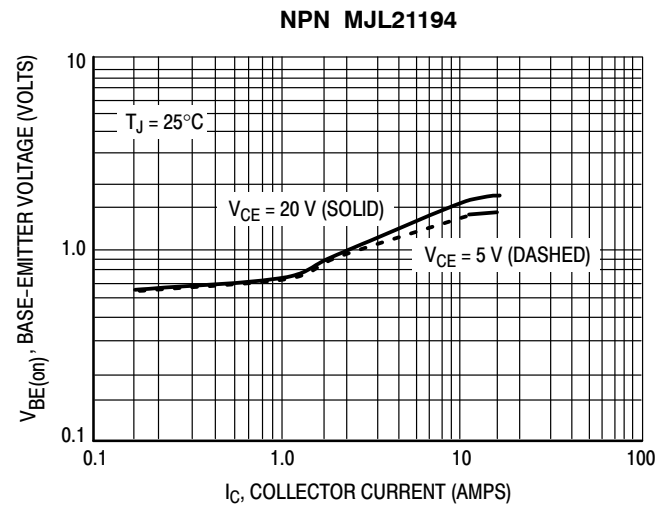


Figure 12. Typical Base-Emitter Voltage

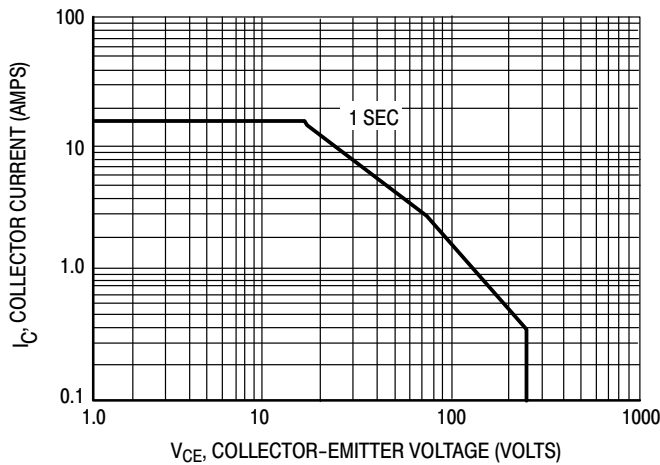


Figure 13. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

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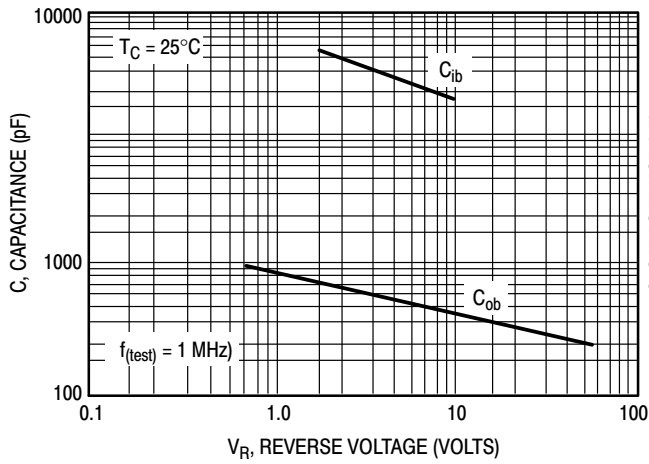


Figure 14. MJL21193 Typical Capacitance

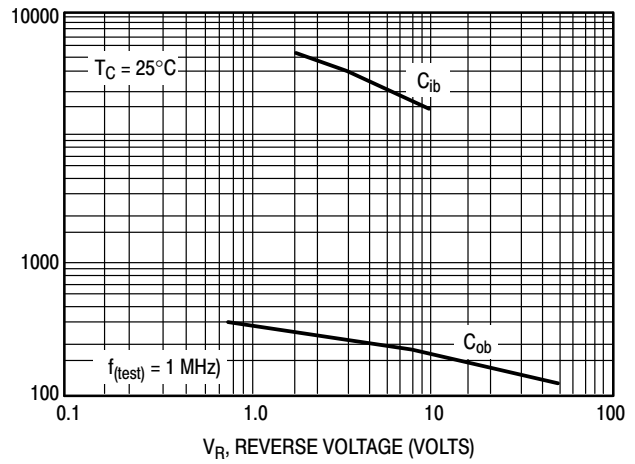


Figure 15. MJL21194 Typical Capacitance

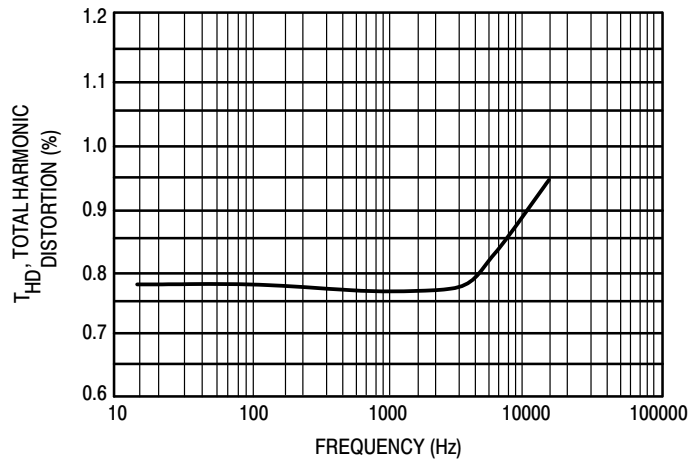


Figure 16. Typical Total Harmonic Distortion

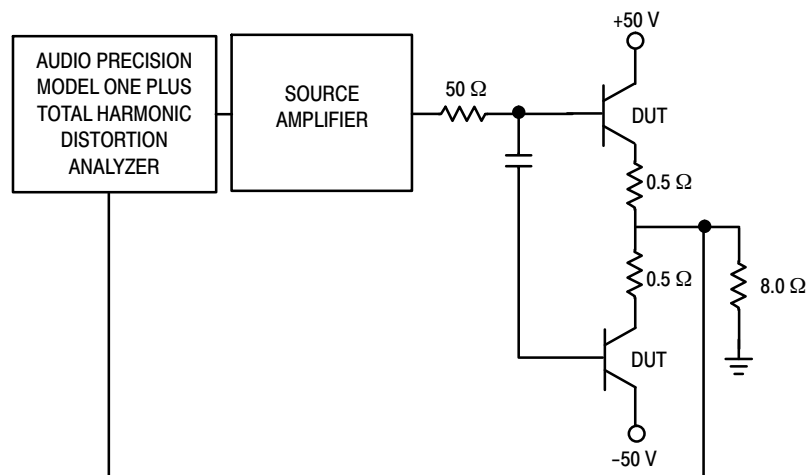
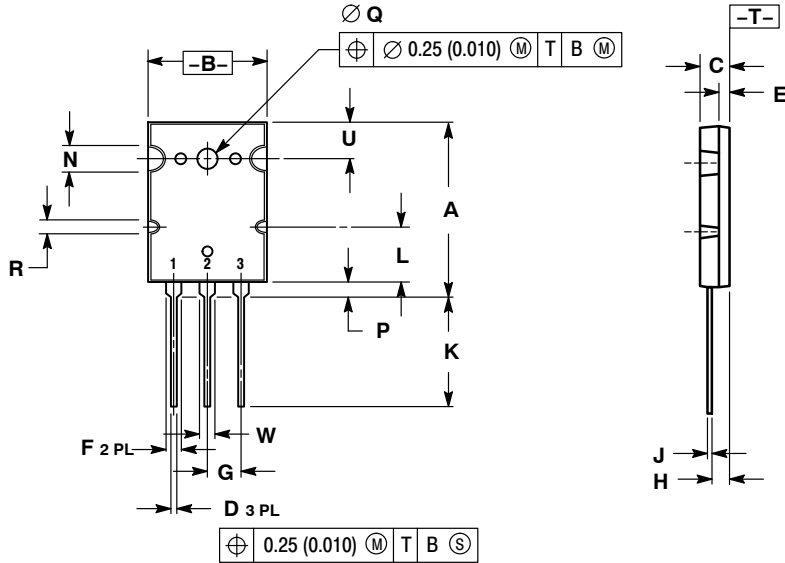


Figure 17. Total Harmonic Distortion Test Circuit

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PACKAGE DIMENSIONS

TO-3BPL (TO-264)
CASE 340G-02
ISSUE J



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 28.0 | 29.0 | 1.102 | 1.142 |
| B | 19.3 | 20.3 | 0.760 | 0.800 |
| C | 4.7 | 5.3 | 0.185 | 0.209 |
| D | 0.93 | 1.48 | 0.037 | 0.058 |
| E | 1.9 | 2.1 | 0.075 | 0.083 |
| F | 2.2 | 2.4 | 0.087 | 0.102 |
| G | 5.45 BSC | | 0.215 BSC | |
| H | 2.6 | 3.0 | 0.102 | 0.118 |
| J | 0.43 | 0.78 | 0.017 | 0.031 |
| K | 17.6 | 18.8 | 0.693 | 0.740 |
| L | 11.2 REF | | 0.411 REF | |
| N | 4.35 REF | | 0.172 REF | |
| P | 2.2 | 2.6 | 0.087 | 0.102 |
| Q | 3.1 | 3.5 | 0.122 | 0.137 |
| R | 2.25 REF | | 0.089 REF | |
| U | 6.3 REF | | 0.248 REF | |
| W | 2.8 | 3.2 | 0.110 | 0.125 |

STYLE 2:

1. BASE
2. COLLECTOR
3. EMITTER

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